

90MHz, 22V/ μ s 16-Bit Accurate Operational Amplifier

August 1998

FEATURES

- 90MHz Gain Bandwidth, $f = 100\text{kHz}$
- 22V/ μ s Slew Rate
- Settling Time: $< 1\mu\text{s}$ ($A_V = -1$, 150 μ V, 10V Step)
- Maximum Input Offset Voltage: 75 μ V
- Maximum Input Offset Voltage Drift: 2 μ V/ $^{\circ}$ C
- Maximum (-) Input Bias Current: 10nA
- Minimum DC Gain: 1000V/mV
- Minimum Output Swing into 2k: $\pm 12.8\text{V}$
- Unity Gain Stable
- Input Noise Voltage: 5nV/ $\sqrt{\text{Hz}}$
- Input Noise Current: 0.6pA/ $\sqrt{\text{Hz}}$
- Low Distortion, -96dBc for 100kHz, 10V_{P-P}
- Specified at $\pm 5\text{V}$ and $\pm 15\text{V}$

APPLICATIONS

- 16-Bit DAC Current-to-Voltage Converter
- Precision Instrumentation
- ADC Buffer
- Low Distortion Active Filters
- High Accuracy Data Acquisition Systems
- Photodiode Amplifiers

DESCRIPTION

The LT[®]1468 is a precision high speed operational amplifier with 16-bit accuracy and less than 1 μ s settling to 150 μ V for 10V signals. This unique blend of precision and AC performance makes the LT1468 the optimum choice for high accuracy data acquisition applications and current-to-voltage conversion. The initial accuracy and drift characteristics of the input offset voltage and inverting input bias current are tailored for inverting applications.

The 90MHz gain bandwidth ensures high open-loop gain at frequency for reducing distortion. In noninverting applications such as an ADC buffer, the low distortion and DC accuracy allow full 16-bit AC and DC performance.

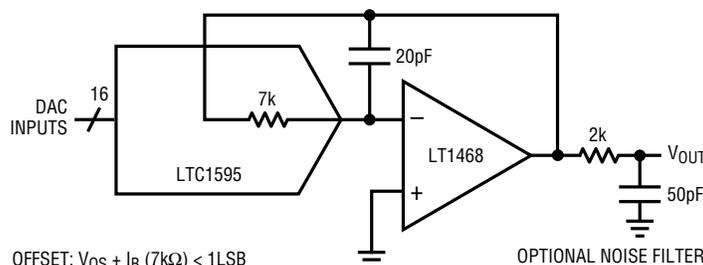
The 22V/ μ s slew rate of the LT1468 improves large signal performance in applications such as active filters and instrumentation amplifiers compared to other precision op amps.

The LT1468 is manufactured on Linear Technology's complementary bipolar process.

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TYPICAL APPLICATION

16-Bit DAC I-to-V Converter



OFFSET: $V_{OS} + I_B (7\text{k}\Omega) < 1\text{LSB}$
 SETTLING TIME TO 150 μ V = 1.8 μ s
 SETTLING LIMITED BY 7k AND 20pF TO COMPENSATE DAC OUTPUT CAPACITANCE

1468 TA01

ABSOLUTE MAXIMUM RATINGS

Total Supply Voltage (V^+ to V^-) 36V
 Maximum Input Current (Note 1) 10mA
 Output Short Circuit Duration (Note 2) Indefinite
 Operating Temperature Range -40°C to 85°C
 Specified Temperature Range (Note 3)... -40°C to 85°C
 Junction Temperature 150°C
 Storage Temperature Range -65°C to 150°C
 Lead Temperature (Soldering, 10 sec.) 300°C

PACKAGE/ORDER INFORMATION

	ORDER PART NUMBER
	LT1468CS8
	S8 PART MARKING
	1468

Consult factory for Industrial and Military Grade parts.

ELECTRICAL CHARACTERISTICS $T_A = 25^{\circ}\text{C}$, $V_{CM} = 0\text{V}$ unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	V_{SUPPLY}	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage		$\pm 15\text{V}$	30	75		μV
			$\pm 5\text{V}$	50	175		μV
I_{OS}	Input Offset Current		$\pm 5\text{V}$ to $\pm 15\text{V}$	15	50		nA
I_{B-}	Inverting Input Bias Current		$\pm 5\text{V}$ to $\pm 15\text{V}$	3	10		nA
I_{B+}	Noninverting Input Bias Current		$\pm 5\text{V}$ to $\pm 15\text{V}$	10	40		nA
e_n	Input Noise Voltage	$f = 10\text{kHz}$	$\pm 5\text{V}$ to $\pm 15\text{V}$	5			$\text{nV}/\sqrt{\text{Hz}}$
i_n	Input Noise Current	$f = 10\text{kHz}$	$\pm 5\text{V}$ to $\pm 15\text{V}$	0.6			$\text{pA}/\sqrt{\text{Hz}}$
R_{IN}	Input Resistance	$V_{CM} = \pm 12.5\text{V}$ Differential	$\pm 15\text{V}$	100	240		$\text{M}\Omega$
			$\pm 5\text{V}$	50	150		$\text{k}\Omega$
C_{IN}	Input Capacitance		$\pm 15\text{V}$	4			pF
	Positive Input Voltage Range		$\pm 15\text{V}$	12.5	13.5		V
			$\pm 5\text{V}$	2.5	3.5		V
	Negative Input Voltage Range		$\pm 15\text{V}$	-14.5	-12.5		V
			$\pm 5\text{V}$	-4.5	-2.5		V
CMRR	Common Mode Rejection Ratio	$V_{CM} = \pm 12.5\text{V}$ $V_{CM} = \pm 2.5\text{V}$	$\pm 15\text{V}$	96	110		dB
			$\pm 5\text{V}$	96	112		dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 4.5\text{V}$ to $\pm 15\text{V}$		100	112		dB
A _{VOL}	Large-Signal Voltage Gain	$V_{OUT} = \pm 12.5\text{V}$, $R_L = 10\text{k}$ $V_{OUT} = \pm 12.5\text{V}$, $R_L = 2\text{k}$ $V_{OUT} = \pm 2.5\text{V}$, $R_L = 10\text{k}$ $V_{OUT} = \pm 2.5\text{V}$, $R_L = 2\text{k}$	$\pm 15\text{V}$	1000	9000		V/mV
			$\pm 15\text{V}$	500	5000		V/mV
			$\pm 5\text{V}$	1000	6000		V/mV
			$\pm 5\text{V}$	500	3000		V/mV
V_{OUT}	Output Swing	$R_L = 10\text{k}$, $V_{IN} = \pm 1\text{mV}$ $R_L = 2\text{k}$, $V_{IN} = \pm 1\text{mV}$ $R_L = 10\text{k}$, $V_{IN} = \pm 1\text{mV}$ $R_L = 2\text{k}$, $V_{IN} = \pm 1\text{mV}$	$\pm 15\text{V}$	± 13.0	± 13.6		V
			$\pm 15\text{V}$	± 12.8	± 13.5		V
			$\pm 5\text{V}$	± 3.0	± 3.6		V
			$\pm 5\text{V}$	± 2.8	± 3.5		V
I_{OUT}	Output Current	$V_{OUT} = \pm 12.5\text{V}$ $V_{OUT} = \pm 2.5\text{V}$	$\pm 15\text{V}$	± 15	± 22		mA
			$\pm 5\text{V}$	± 15	± 22		mA
I_{SC}	Short-Circuit Current	$V_{OUT} = 0\text{V}$, $V_{IN} = \pm 0.2\text{V}$	$\pm 15\text{V}$	± 25	± 40		mA
SR	Slew Rate	$A_V = -1$, $R_L = 2\text{k}$ (Note 4)	$\pm 15\text{V}$	15	22		$\text{V}/\mu\text{s}$
			$\pm 5\text{V}$	11	17		$\text{V}/\mu\text{s}$
	Full-Power Bandwidth	10V peak, (Note 5) 3V peak, (Note 5)	$\pm 15\text{V}$	350			kHz
			$\pm 5\text{V}$	900			kHz

ELECTRICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_{CM} = 0\text{V}$ unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	V _{SUPPLY}	MIN	TYP	MAX	UNITS
GBW	Gain Bandwidth	$f = 100\text{kHz}$, $R_L = 2\text{k}$	$\pm 15\text{V}$	60	90		MHz
			$\pm 5\text{V}$	55	85		MHz
t_r , t_f	Rise Time, Fall Time	$A_V = 1$, 10% to 90%, 0.1V	$\pm 15\text{V}$		11		ns
			$\pm 5\text{V}$		12		ns
	Overshoot	$A_V = 1$, 0.1V	$\pm 15\text{V}$		30		%
			$\pm 5\text{V}$		35		%
	Propagation Delay	$A_V = 1$, 50% V_{IN} to 50% V_{OUT} , 0.1V	$\pm 15\text{V}$		9		ns
			$\pm 5\text{V}$		10		ns
t_s	Settling Time	10V Step, 0.01%, $A_V = -1$ 10V Step, 150 μV , $A_V = -1$ 5V Step, 0.01%, $A_V = -1$	$\pm 15\text{V}$		760		ns
			$\pm 15\text{V}$		900		ns
			$\pm 5\text{V}$		780		ns
R_O	Output Resistance	$A_V = 1$, $f = 100\text{kHz}$	$\pm 15\text{V}$		0.02		Ω
I_S	Supply Current		$\pm 15\text{V}$		3.9	5.2	mA
			$\pm 5\text{V}$		3.6	5.0	mA

$0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$, $V_{CM} = 0\text{V}$ unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	V _{SUPPLY}	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage		$\pm 15\text{V}$			150	μV
			$\pm 5\text{V}$			250	μV
	Input V_{OS} Drift	(Note 6)	$\pm 5\text{V}$ to $\pm 15\text{V}$		0.7	2.0	$\mu\text{V}/^\circ\text{C}$
I_{OS}	Input Offset Current		$\pm 5\text{V}$ to $\pm 15\text{V}$			65	nA
					60		$\text{pA}/^\circ\text{C}$
I_{B-}	Inverting Input Bias Current		$\pm 5\text{V}$ to $\pm 15\text{V}$			15	nA
					40		$\text{pA}/^\circ\text{C}$
I_{B+}	Noninverting Input Bias Current		$\pm 5\text{V}$ to $\pm 15\text{V}$			50	nA
CMRR	Common Mode Rejection Ratio	$V_{CM} = \pm 12.5\text{V}$ $V_{CM} = \pm 2.5\text{V}$	$\pm 15\text{V}$	94			dB
			$\pm 5\text{V}$	94			dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 4.5\text{V}$ to $\pm 15\text{V}$		98			dB
A_{VOL}	Large-Signal Voltage Gain	$V_{OUT} = \pm 12.5\text{V}$, $R_L = 10\text{k}$ $V_{OUT} = \pm 12.5\text{V}$, $R_L = 2\text{k}$ $V_{OUT} = \pm 2.5\text{V}$, $R_L = 10\text{k}$ $V_{OUT} = \pm 2.5\text{V}$, $R_L = 2\text{k}$	$\pm 15\text{V}$	500			V/mV
			$\pm 15\text{V}$	250			V/mV
			$\pm 5\text{V}$	500			V/mV
			$\pm 5\text{V}$	250			V/mV
V_{OUT}	Output Swing	$R_L = 10\text{k}$, $V_{IN} = \pm 1\text{mV}$ $R_L = 2\text{k}$, $V_{IN} = \pm 1\text{mV}$ $R_L = 10\text{k}$, $V_{IN} = \pm 1\text{mV}$ $R_L = 2\text{k}$, $V_{IN} = \pm 1\text{mV}$	$\pm 15\text{V}$	± 12.9			V
			$\pm 15\text{V}$	± 12.7			V
			$\pm 5\text{V}$	± 2.9			V
			$\pm 5\text{V}$	± 2.7			V
I_{OUT}	Output Current	$V_{OUT} = \pm 12.5\text{V}$ $V_{OUT} = \pm 2.5\text{V}$	$\pm 15\text{V}$	± 12.5			mA
			$\pm 5\text{V}$	± 12.5			mA
I_{SC}	Short-Circuit Current	$V_{OUT} = 0\text{V}$, $V_{IN} = \pm 0.2\text{V}$	$\pm 15\text{V}$	± 17			mA
SR	Slew Rate	$A_V = -1$, $R_L = 2\text{k}$ (Note 4)	$\pm 15\text{V}$	13			V/ μs
			$\pm 5\text{V}$	9			V/ μs
GBW	Gain Bandwidth	$f = 100\text{kHz}$, $R_L = 2\text{k}$	$\pm 15\text{V}$	55			MHz
			$\pm 5\text{V}$	50			MHz
I_S	Supply Current		$\pm 15\text{V}$			6.5	mA
			$\pm 5\text{V}$			6.3	mA

ELECTRICAL CHARACTERISTICS $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, $V_{\text{CM}} = 0\text{V}$ unless otherwise noted (Note 3).

SYMBOL	PARAMETER	CONDITIONS	V_{SUPPLY}	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage		$\pm 15\text{V}$ $\pm 5\text{V}$			230 330	μV μV
	Input V_{OS} Drift	(Note 6)	$\pm 5\text{V}$ to $\pm 15\text{V}$		0.7	2.5	$\mu\text{V}/^{\circ}\text{C}$
I_{OS}	Input Offset Current		$\pm 5\text{V}$ to $\pm 15\text{V}$			80	nA
	Input Offset Current Drift				120		$\text{pA}/^{\circ}\text{C}$
$I_{\text{B-}}$	Inverting Input Bias Current		$\pm 5\text{V}$ to $\pm 15\text{V}$			30	nA
	Negative Input Current Drift				80		$\text{pA}/^{\circ}\text{C}$
$I_{\text{B+}}$	Noninverting Input Bias Current		$\pm 5\text{V}$ to $\pm 15\text{V}$			60	nA
CMRR	Common Mode Rejection Ratio	$V_{\text{CM}} = \pm 12.5\text{V}$	$\pm 15\text{V}$	92			dB
		$V_{\text{CM}} = \pm 2.5\text{V}$	$\pm 5\text{V}$	92			dB
PSRR	Power Supply Rejection Ratio	$V_{\text{S}} = \pm 4.5\text{V}$ to $\pm 15\text{V}$		96			dB
A_{VOL}	Large-Signal Voltage Gain	$V_{\text{OUT}} = \pm 12\text{V}$, $R_{\text{L}} = 10\text{k}$	$\pm 15\text{V}$	300			V/mV
		$V_{\text{OUT}} = \pm 10\text{V}$, $R_{\text{L}} = 2\text{k}$	$\pm 15\text{V}$	150			V/mV
		$V_{\text{OUT}} = \pm 2.5\text{V}$, $R_{\text{L}} = 10\text{k}$	$\pm 5\text{V}$	300			V/mV
		$V_{\text{OUT}} = \pm 2.5\text{V}$, $R_{\text{L}} = 2\text{k}$	$\pm 5\text{V}$	150			V/mV
V_{OUT}	Output Swing	$R_{\text{L}} = 10\text{k}$, $V_{\text{IN}} = \pm 1\text{mV}$	$\pm 15\text{V}$	± 12.8			V
		$R_{\text{L}} = 2\text{k}$, $V_{\text{IN}} = \pm 1\text{mV}$	$\pm 15\text{V}$	± 12.6			V
		$R_{\text{L}} = 10\text{k}$, $V_{\text{IN}} = \pm 1\text{mV}$	$\pm 5\text{V}$	± 2.8			V
		$R_{\text{L}} = 2\text{k}$, $V_{\text{IN}} = \pm 1\text{mV}$	$\pm 5\text{V}$	± 2.6			V
I_{OUT}	Output Current	$V_{\text{OUT}} = \pm 12.5\text{V}$	$\pm 15\text{V}$	± 8			mA
		$V_{\text{OUT}} = \pm 2.5\text{V}$	$\pm 5\text{V}$	± 8			mA
I_{SC}	Short-Circuit Current	$V_{\text{OUT}} = 0\text{V}$, $V_{\text{IN}} = \pm 0.2\text{V}$	$\pm 15\text{V}$	± 12			mA
SR	Slew Rate	$A_{\text{V}} = -1$, $R_{\text{L}} = 2\text{k}$ (Note 4)	$\pm 15\text{V}$	10			$\text{V}/\mu\text{s}$
			$\pm 5\text{V}$	7			$\text{V}/\mu\text{s}$
GBW	Gain Bandwidth	$f = 100\text{kHz}$, $R_{\text{L}} = 2\text{k}$	$\pm 15\text{V}$	45			MHz
			$\pm 5\text{V}$	40			MHz
I_{S}	Supply Current		$\pm 15\text{V}$			7.0	mA
			$\pm 5\text{V}$			6.8	mA

Note 1: The inputs are protected by back-to-back diodes and two 100Ω series resistors. If the differential input voltage exceeds 0.7V , the input current should be limited to 10mA . Input voltages outside the supplies will be clamped by ESD protection devices and input currents should also be limited to 10mA .

Note 2: A heat sink may be required to keep the junction temperature below absolute maximum when the output is shorted indefinitely.

Note 3: The LT1468 is designed, characterized and expected to meet these extended temperature limits, but is not tested at -40°C and at 85°C . Consult factory for guaranteed I grade parts.

Note 4: Slew rate is measured between $\pm 8\text{V}$ on the output with $\pm 12\text{V}$ input for $\pm 15\text{V}$ supplies and $\pm 2\text{V}$ on the output with $\pm 3\text{V}$ input for $\pm 5\text{V}$ supplies.

Note 5: Full power bandwidth is calculated from the slew rate measurement: $\text{FPBW} = \text{SR}/2\pi V_{\text{P}}$

Note 6: This parameter is not 100% tested.